Docket No.: 5882P063

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re the Application of:

DAE WOO LEE, ET AL.

Application No.:

Filed:

For: Structure of High Voltage Device and Low

Voltage Device, and Method of Manufacturing the Same

Art Group:

Examiner:

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.97

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure, enclosed is a copy of Information Disclosure Statement by Applicant (form PTO/SB/08), which is being submitted. It is respectfully requested that the cited references be considered and that the enclosed copy of PTO/SB/08 be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant(s).

The submission of this Information Disclosure Statement is not to be construed as a representation that a search has been made in the subject application and is not to be construed as an admission that the information cited in this statement is material to patentability.

Respectfully submitted,

Blakely, Søkoloff, Taylor & Zafman LLF

Eric S. Hyman, Reg. No. 30,139

Date: November 29 2003

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| Substitute | for form 1449A/PTO | | | | Complete if Known | | |
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| INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary) | | | | Application Number | | | |
| | | | | Filing Date | | | |
| | | | | First Named Inventor | Dae Woo Lee | | |
| | | | | Art Unit | | | |
| | | | | Examiner Name | | | |
| Sheet | 1 | of | 2 | Attorney Docket Number | 5882P063 | | |

| U.S. PATENT DOCUMENTS | | | | | | | |
|-----------------------|--------------|---|---|--|---|--|--|
| Examiner Initials* | Cite No.1 | Document Number Number - Kind Code ² (if known) | Publication Date or Issue Date MM-DD-YYYY | Name of Patentee or Applicant of Cited Document | Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear | | |
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| FOREIGN PATENT DOCUMENTS | | | | | | | | |
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| Examiner Initials* Cite | Foreign Patent Document | | | Pages Columns Lines | Ι. | | | |
| | Country Code ³ - Number ⁴ - Kind Code ⁵ (if known) | Publication Date MM-DD-YYYY | Name of Patentee or Applicant of Cited Document | Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear | T° | | | |
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*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

¹Applicant's unique citation designation number (optional). ²See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English language Translation is attached.

Based on PTO/SB/08A (08-03) as modified by Blakely, Solokoff, Taylor & Zafman (wlr) 08/11/2003.

| Substitute fo | or form 1449A/PTO | | | Complete if Known | | |
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| | | | | Filing Date | | |
| | | | | First Named Inventor | Dae Woo Lee | |
| | | | | Art Unit | | |
| (use as many sneets as necessary) | | | | Examiner Name | | |
| Sheet | 2 | of | 2 | Attorney Docket Number | 5882P063 | |

| NON PATENT LITERATURE DOCUMENTS | | | | | |
|---------------------------------|--------------|---|----|--|--|
| Examiner Initials* | Cite No.¹ | Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published. | T² | | |
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